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<u>Vishay Semiconductor/Diodes Division</u> <u>S1AHE3_A/I</u>

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of S1AHE3_A/I - DIODE GEN PURP 50V 1A DO214AC

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Vishay General Semiconductor

Surface Mount Glass Passivated Rectifier



DO-214AC (SMA)

PRIMARY CHARACTERISTICS							
I _{F(AV)}	1.0 A						
V _{RRM}	50 V, 100 V, 200 V, 400 V, 600 V, 800 V, 1000 V						
I _{FSM}	40 A, 30 A						
E _{AS}	5 mJ						
I _R	1.0 μΑ, 5.0 μΑ						
V _F	1.1 V						
T _J max.	150 °C						
Package	DO-214AC (SMA)						
Diode variations	Single die						

FEATURES

- Low profile package
- Ideal for automated placement
- · Glass passivated pellet chip junction
- · Low forward voltage drop
- · Low leakage current
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes for consumer, automotive, and telecommunication.

MECHANICAL DATA

Case: DO-214AC (SMA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHSp-compliant, commercial grade Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,.....)

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)									
PARAMETER	SYMBOL	S1A	S1B	S1D	S1G	S1J	S1K	S1M	UNIT
Device marking code		SA	SB	SD	SG	SJ	SK	SM	
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	1.0					Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	40 30				80	Α		
Non-repetitive peak reverse avalanche energy at 25 °C, I _{AS} = 1 A, L = 10 mH	E _{AS}	5					mJ		
Operating junction and storage temperature range	T_J , T_{STG}	-55 to +150					°C		

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)											
PARAMETER	TEST (CONDITIONS	SYMBOL	S1A	S1B	S1D	S1G	S1J	S1K	S1M	UNIT
Maximum instantaneous forward voltage	1.0 A		V _F	1.1					V		
Maximum DC reverse current		T _A = 25 °C		1.0 5.0						.0	
at rated DC blocking voltage		T _A = 125 °C	IR	50							μA
Typical reverse recovery time	I _F = 0.5 I _{rr} = 0.2	A, I _R = 1.0 A, 5 A	t _{rr}	1.8				μs			
Typical junction capacitance	4.0 V, 1	MHz	CJ	12						pF	

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)									
PARAMETER	SYMBOL S1A S1B S1D S1G S1J S1K S1M UNIT						UNIT		
Typical thermal resistance (1)	$R_{\theta JA}$	75					85		°C/W
Typical thermal resistance 17	$R_{\theta JL}$	27					30		C/VV

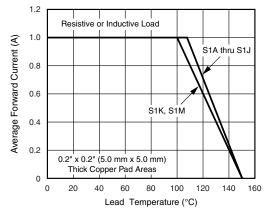
Note

⁽¹⁾ Thermal resistance from junction to ambient and from junction to lead mounted on PCB with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

ORDERING INFORMATION (Example)									
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE					
S1J-E3/61T	0.064	61T	1800	7" diameter plastic tape and reel					
S1J-E3/5AT	0.064	5AT	7500	13" diameter plastic tape and reel					
S1JHE3_A/H (1)	0.064	Н	1800	7" diameter plastic tape and reel					
S1JHE3_A/I (1)	0.064	I	7500	13" diameter plastic tape and reel					

Note

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)





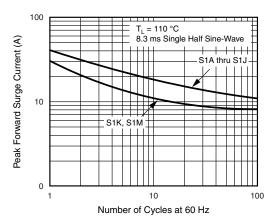


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

⁽¹⁾ AEC-Q101 qualified



S1A, S1B, S1D, S1G, S1J, S1K, S1M

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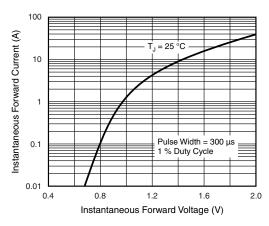


Fig. 3 - Typical Instantaneous Forward Characteristics

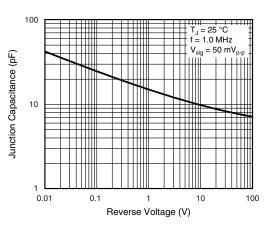


Fig. 5 - Typical Junction Capacitance

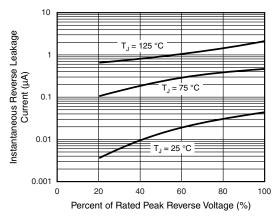


Fig. 4 - Typical Reverse Leakage Characteristics

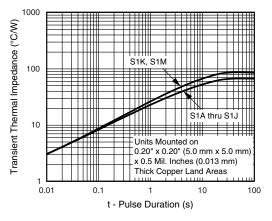
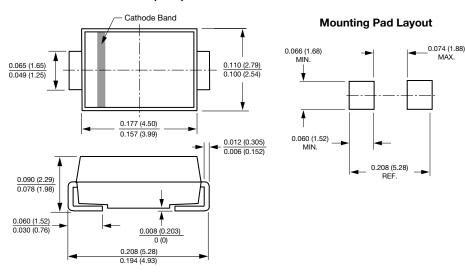


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-214AC (SMA)



Revision: 16-Feb-16 3 Document Number: 88711



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Revision: 13-Jun-16 1 Document Number: 91000